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CONTENTS

Priority Communication

LP-MOCVD growth of BGaAsSb thick layers and BGaAs-Sb/GaAs quantum well structures on GaAs (001) substrates
Z. Jia, Q. Wang, X. Ren, Y. Wang, S. Cai, X. Zhang and Y. Huang

Classical semiconductors

Efficiency improvement of InGaN light emitting diodes with embedded self-assembled SiO₂ nanosphere arrays
Y. Zhang, T. Wei, J. Wang, C. Fan, Y. Chen, Q. Hu and J. Li

HVPE-GaN grown on MOCVD-GaN/sapphire template and ammonothermal GaN seeds: Comparison of structural, optical, and electrical properties
T. Sochacki, Z. Bryan, M. Amilusik, M. Bobea, M. Fijalkowski, I. Bryan, B. Lucznik, R. Collazo, J.L. Weyher, R. Kucharski, I. Grzegory, M. Bockowski and Z. Sitar

Effects of argon pressure and r.f. power on magnetron sputtered aluminum doped ZnO thin films
N. Evcimen Duygulu, A.O. Kodolbas and A. Ekerim

Microstructure and Raman scattering of Ag-doping ZnO films deposited on buffer layers
H.Q. Bian, S.Y. Ma, Z.M. Zhang, J.M. Gao and H.B. Zhu

Numerical and experimental evaluations on new direct growth process of polycrystalline silicon wafer from liquid silicon
B. Jang, S. Shin, J. Lee and J. Kim

Electronic materials

Vapour growth and characterization of beta indium sesquitelluride crystals
P.M. Reshmi, A.G. Kunjomana, K.A. Chandrasekharan and M. Teena

Facet growth of self-separated GaN layers through HVPE on large square-patterned template
Y. Sui, B. Wang, Z. Zhao, W. Xu, X. Li, X. Wang and G. Yu

Deposition of binary, ternary and quaternary metal selenide thin films from diisopropyldiselenophosphinato-metal precursors
S. Mahboob, S.N. Malik, N. Haider, C. Q. Nguyen, M.A. Malik and P. O'Brien

Correlation between soft annealing conditions and structural, microstructural, morphological, and optical properties of CuInS₂ thin films prepared by sulfurization of stacked precursor
S.W. Shin, K.V. Gurav, M.G. Gang, M.P. Suryawanshi, P.S. Patil, G.L. Agawane, C.H. Jeoung, J.H. Yun, J.Y. Lee and J.H. Kim

Step flow and polytype transformation in growth of 4H-SiC crystals
C. Liu, X. Chen, T. Peng, B. Wang, W. Wang and G. Wang

126

Solution growth; industrial biological and molecular crystallization

74 Phase determination of zinc selenide nanocrystals depending on the ligand species of precursor complexes
T. Omata, H. Uesugi and M. Kita

81

7 Effect of sample size on intermetallic Al₂Cu microstructure and orientation evolution during directional solidification
K. Gao, S. Li, L. Xu and H. Fu

89

Systematic classification of unseeded batch crystallization systems for achievable shape and size analysis
D. Acevedo and Z.K. Nagy

97

55 Solubility measurement of a metastable achiral crystal of sodium chlorate in solution growth
H. Niinomi, A. Horio, S. Harada, T. Ujihara, H. Miura, Y. Kimura and K. Tsukamoto

106

General subjects

Thermodynamic evaluation of segregation behaviors of metallic impurities in metallurgical grade silicon during Al-Si solvent refining process
J. Li and Z. Guo

18

145 Dendritic growth kinetics and disorder trapping of the intermetallic compound Ni₃Sn under a static magnetic field
C. Yang and J. Gao

24

Microstructural evolution in Mg-Zn alloys during solidification: An experimental and simulation study
M. Paliwal and I.-H. Jung

28

11 Growth and characterization of CePtIn single crystal
M. Klicpera, J. Pospíšil, A. Rudajevová, A. Hoser and P. Javorský

61

39 Evidence for two growth modes during tungsten oxide vapor deposition on mica substrates
K. Mašek, M. Gillet and V. Matolín

67

Epitaxial Co metal thin film grown by pulsed laser deposition using oxide target
D.S. Negi, A. Roy, B. Loukya, K. Dileep, S. Shetty, N. Kumar, P.S.A. Kumar and R. Datta

112

49 Calcite growth: Rate dependence on saturation, on ratios of dissolved calcium and (bi)carbonate and on their complexes
C.H. van der Weijden and R.D. van der Weijden

137

